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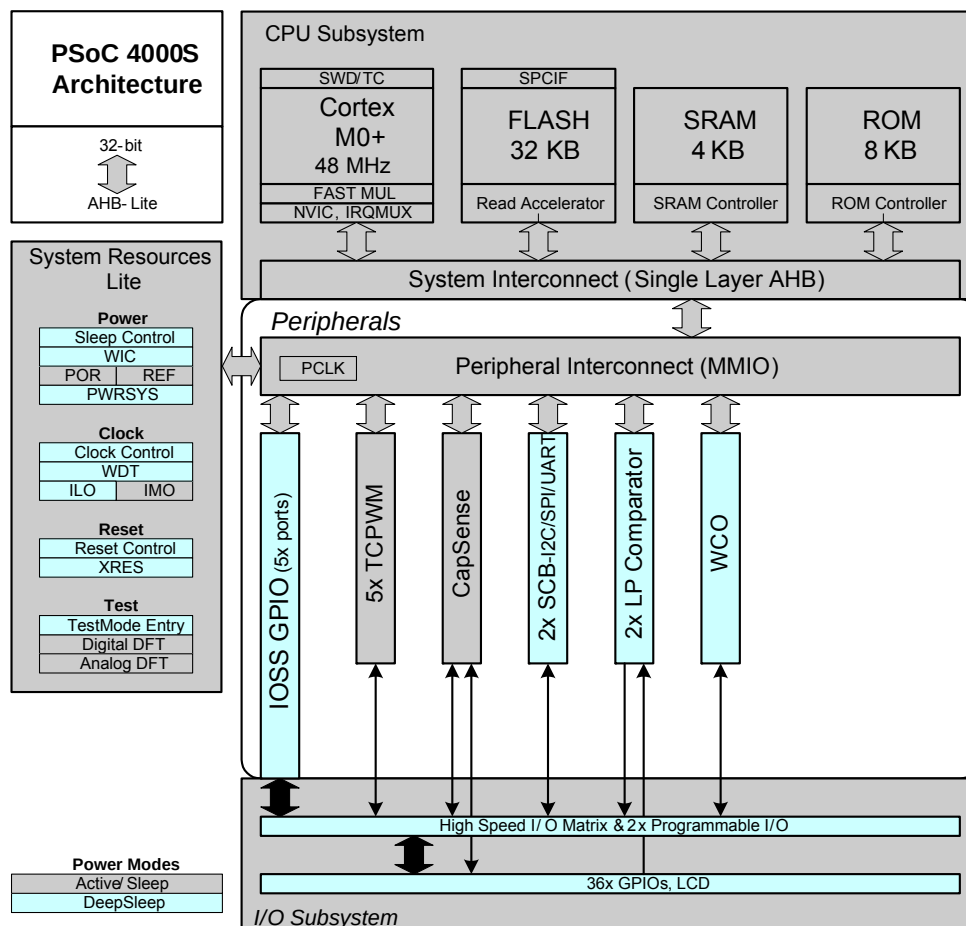
What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I²C, IrDA, LINbus, Microwire, SmartCard, SPI, SSP, UART/USART
Peripherals	Brown-out Detect/Reset, CapSense, LCD, LVD, POR, PWM, WDT
Number of I/O	36
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	A/D 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-TQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/infiniteon-technologies/cy8c4045azi-s413

Figure 1. Block Diagram


PSoC 4000S devices include extensive support for programming, testing, debugging, and tracing both hardware and firmware.

The ARM Serial-Wire Debug (SWD) interface supports all programming and debug features of the device.

Complete debug-on-chip functionality enables full-device debugging in the final system using the standard production device. It does not require special interfaces, debugging pods, simulators, or emulators. Only the standard programming connections are required to fully support debug.

The PSoC Creator IDE provides fully integrated programming and debug support for the PSoC 4000S devices. The SWD interface is fully compatible with industry-standard third-party tools. The PSoC 4000S family provides a level of security not possible with multi-chip application solutions or with microcontrollers. It has the following advantages:

- Allows disabling of debug features
- Robust flash protection
- Allows customer-proprietary functionality to be implemented in on-chip programmable blocks

The debug circuits are enabled by default and can be disabled in firmware. If they are not enabled, the only way to re-enable them is to erase the entire device, clear flash protection, and reprogram the device with new firmware that enables debugging. Thus firmware control of debugging cannot be over-ridden without erasing the firmware thus providing security.

Additionally, all device interfaces can be permanently disabled (device security) for applications concerned about phishing attacks due to a maliciously reprogrammed device or attempts to defeat security by starting and interrupting flash programming sequences. All programming, debug, and test interfaces are disabled when maximum device security is enabled. Therefore, PSoC 4000S, with device security enabled, may not be returned for failure analysis. This is a trade-off the PSoC 4000S allows the customer to make.

Table 1. PSoC 4000S Pin List *(continued)*

48-TQFP		32-QFN		24-QFN		25-CSP		40-QFN	
Pin	Name	Pin	Name	Pin	Name	Pin	Name	Pin	Name
17	P3.4							14	P3.4
18	P3.5							15	P3.5
19	P3.6							16	P3.6
20	P3.7							17	P3.7
21	VDDD								
22	P4.0	13	P4.0	9	P4.0	E3	P4.0	18	P4.0
23	P4.1	14	P4.1	10	P4.1	D2	P4.1	19	P4.1
24	P4.2	15	P4.2	11	P4.2	E2	P4.2	20	P4.2
25	P4.3	16	P4.3	12	P4.3	E1	P4.3	21	P4.3

Descriptions of the Pin functions are as follows:

VDDD: Power supply for the digital section.

VDDA: Power supply for the analog section.

VSSD, VSSA: Ground pins for the digital and analog sections respectively.

VCCD: Regulated digital supply (1.8 V $\pm$ 5%)

VDD: Power supply to all sections of the chip

VSS: Ground for all sections of the chip

Alternate Pin Functions

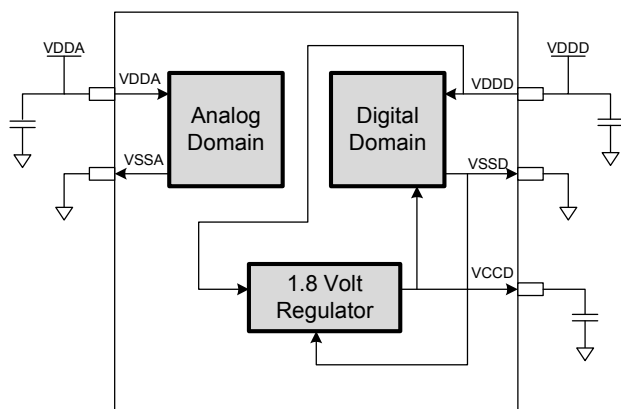
Each port pin can be assigned to one of multiple functions; it can, for instance, be an analog I/O, a digital peripheral function, an LCD pin, or a CapSense pin. The pin assignments are shown in the following table.

Port/ Pin	Analog	Smart I/O	Alternate Function 1	Alternate Function 2	Alternate Function 3	Deep Sleep 1	Deep Sleep 2
P0.0	lpcomp.in_p[0]				tcpwm.tr_in[0]		scb[0].spi_select1:0
P0.1	lpcomp.in_n[0]				tcpwm.tr_in[1]		scb[0].spi_select2:0
P0.2	lpcomp.in_p[1]						scb[0].spi_select3:0
P0.3	lpcomp.in_n[1]						
P0.4	wco.wco_in			scb[1].uart_rx:0		scb[1].i2c_scl:0	scb[1].spi_mosi:1
P0.5	wco.wco_out			scb[1].uart_tx:0		scb[1].i2c_sda:0	scb[1].spi_miso:1
P0.6			srss.ext_clk	scb[1].uart_cts:0			scb[1].spi_clk:1
P0.7				scb[1].uart_rts:0			scb[1].spi_select0:1
P1.0			tcpwm.line[2]:1	scb[0].uart_rx:1		scb[0].i2c_scl:0	scb[0].spi_mosi:1
P1.1			tcpwm.line_compl[2]:1	scb[0].uart_tx:1		scb[0].i2c_sda:0	scb[0].spi_miso:1
P1.2			tcpwm.line[3]:1	scb[0].uart_cts:1	tcpwm.tr_in[2]		scb[0].spi_clk:1
P1.3			tcpwm.line_compl[3]:1	scb[0].uart_rts:1	tcpwm.tr_in[3]		scb[0].spi_select0:1
P1.4							scb[0].spi_select1:1
P1.5							scb[0].spi_select2:1

Power

The following power system diagram shows the set of power supply pins as implemented for the PSoC 4000S. The system has one regulator in Active mode for the digital circuitry. There is no analog regulator; the analog circuits run directly from the V_{DD} input.

Figure 3. Power Supply Connections



There are two distinct modes of operation. In Mode 1, the supply voltage range is 1.8 V to 5.5 V (unregulated externally; internal regulator operational). In Mode 2, the supply range is $1.8 \text{ V} \pm 5\%$ (externally regulated; 1.71 to 1.89, internal regulator bypassed).

Mode 1: 1.8 V to 5.5 V External Supply

In this mode, the PSoC 4000S is powered by an external power supply that can be anywhere in the range of 1.8 to 5.5 V. This range is also designed for battery-powered operation. For example, the chip can be powered from a battery system that starts at 3.5 V and works down to 1.8 V. In this mode, the internal regulator of the PSoC 4000S supplies the internal logic and its output is connected to the V_{CCD} pin. The V_{CCD} pin must be bypassed to ground via an external capacitor (0.1 μF ; X5R ceramic or better) and must not be connected to anything else.

Mode 2: 1.8 V $\pm 5\%$ External Supply

In this mode, the PSoC 4000S is powered by an external power supply that must be within the range of 1.71 to 1.89 V; note that this range needs to include the power supply ripple too. In this mode, the V_{DD} and V_{CCD} pins are shorted together and bypassed. The internal regulator can be disabled in the firmware.

Bypass capacitors must be used from V_{DDD} to ground. The typical practice for systems in this frequency range is to use a capacitor in the 1- μF range, in parallel with a smaller capacitor (0.1 μF , for example). Note that these are simply rules of thumb and that, for critical applications, the PCB layout, lead inductance, and the bypass capacitor parasitic should be simulated to design and obtain optimal bypassing.

An example of a bypass scheme is shown in the following diagram.

Figure 4. External Supply Range from 1.8 V to 5.5 V with Internal Regulator Active

Power supply bypass connections example

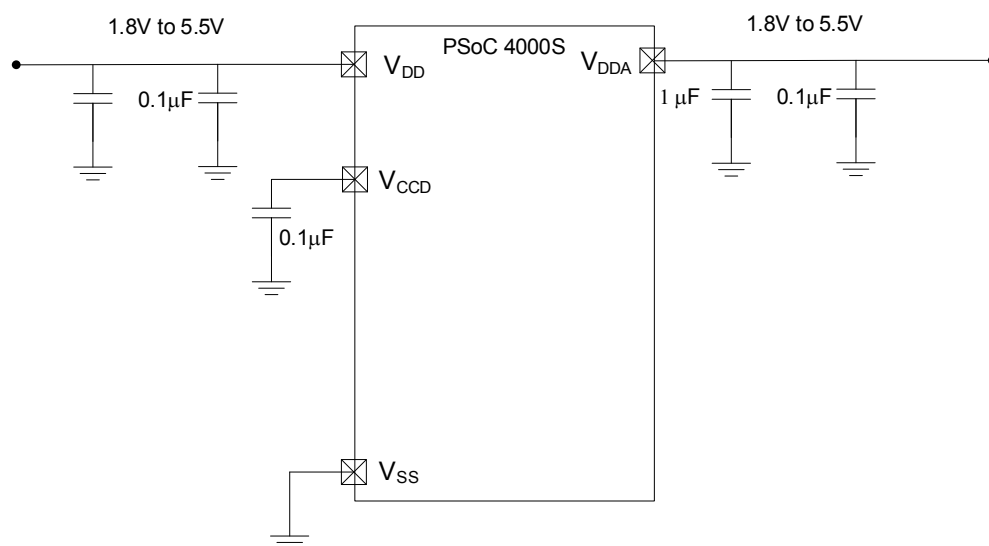


Table 3. DC Specifications (continued)

Typical values measured at $V_{DD} = 3.3\text{ V}$ and $25\text{ }^{\circ}\text{C}$.

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
Sleep Mode, $V_{DDD} = 1.71\text{ V}$ to 1.89 V (Regulator bypassed)							
SID28	I_{DD23}	I ² C wakeup, WDT, and Comparators on	–	0.7	0.9	mA	6 MHz
SID28A	I_{DD23A}	I ² C wakeup, WDT, and Comparators on	–	0.9	1.1	mA	12 MHz
Deep Sleep Mode, $V_{DD} = 1.8\text{ V}$ to 3.6 V (Regulator on)							
SID31	I_{DD26}	I ² C wakeup and WDT on	–	2.5	60	μA	–
Deep Sleep Mode, $V_{DD} = 3.6\text{ V}$ to 5.5 V (Regulator on)							
SID34	I_{DD29}	I ² C wakeup and WDT on	–	2.5	60	μA	–
Deep Sleep Mode, $V_{DD} = V_{CCD} = 1.71\text{ V}$ to 1.89 V (Regulator bypassed)							
SID37	I_{DD32}	I ² C wakeup and WDT on	–	2.5	60	μA	–
XRES Current							
SID307	I_{DD_XR}	Supply current while XRES asserted	–	2	5	mA	–

Table 4. AC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID48	F_{CPU}	CPU frequency	DC	–	48	MHz	$1.71 \leq V_{DD} \leq 5.5$
SID49 ^[3]	T_{SLEEP}	Wakeup from Sleep mode	–	0	–	μs	
SID50 ^[3]	$T_{DEEPSLEEP}$	Wakeup from Deep Sleep mode	–	35	–		

Note

2. Guaranteed by characterization.

GPIO

Table 5. GPIO DC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID57	$V_{IH}^{[3]}$	Input voltage high threshold	$0.7 \times V_{DD}$	–	–	V	CMOS Input
SID58	V_{IL}	Input voltage low threshold	–	–	$0.3 \times V_{DD}$		CMOS Input
SID241	$V_{IH}^{[3]}$	LVTTL input, $V_{DD} < 2.7$ V	$0.7 \times V_{DD}$	–	–		–
SID242	V_{IL}	LVTTL input, $V_{DD} < 2.7$ V	–	–	$0.3 \times V_{DD}$		–
SID243	$V_{IH}^{[3]}$	LVTTL input, $V_{DD} \geq 2.7$ V	2.0	–	–		–
SID244	V_{IL}	LVTTL input, $V_{DD} \geq 2.7$ V	–	–	0.8		–
SID59	V_{OH}	Output voltage high level	$V_{DD} - 0.6$	–	–		$I_{OH} = 4$ mA at 3 V V_{DD}
SID60	V_{OH}	Output voltage high level	$V_{DD} - 0.5$	–	–		$I_{OH} = 1$ mA at 3 V V_{DD}
SID61	V_{OL}	Output voltage low level	–	–	0.6		$I_{OL} = 4$ mA at 1.8 V V_{DD}
SID62	V_{OL}	Output voltage low level	–	–	0.6		$I_{OL} = 10$ mA at 3 V V_{DD}
SID62A	V_{OL}	Output voltage low level	–	–	0.4		$I_{OL} = 3$ mA at 3 V V_{DD}
SID63	R_{PULLUP}	Pull-up resistor	3.5	5.6	8.5	k Ω	–
SID64	$R_{PULLDOWN}$	Pull-down resistor	3.5	5.6	8.5		–
SID65	I_{IL}	Input leakage current (absolute value)	–	–	2	nA	25 °C, $V_{DD} = 3.0$ V
SID66	C_{IN}	Input capacitance	–	–	7	pF	–
SID67 ^[4]	V_{HYSTTL}	Input hysteresis LVTTL	25	40	–	mV	$V_{DD} \geq 2.7$ V
SID68 ^[4]	$V_{HYSCMOS}$	Input hysteresis CMOS	$0.05 \times V_{DD}$	–	–		$V_{DD} < 4.5$ V
SID68A ^[4]	$V_{HYSCMOS5V5}$	Input hysteresis CMOS	200	–	–		$V_{DD} > 4.5$ V
SID69 ^[4]	I_{DIODE}	Current through protection diode to V_{DD}/V_{SS}	–	–	100	μ A	–
SID69A ^[4]	I_{TOT_GPIO}	Maximum total source or sink chip current	–	–	200	mA	–

Table 6. GPIO AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID70	T_{RISEF}	Rise time in fast strong mode	2	–	12	ns	3.3 V V_{DD} , Load = 25 pF
SID71	T_{FALLF}	Fall time in fast strong mode	2	–	12		3.3 V V_{DD} , Load = 25 pF
SID72	T_{RISES}	Rise time in slow strong mode	10	–	60	–	3.3 V V_{DD} , Load = 25 pF
SID73	T_{FALLS}	Fall time in slow strong mode	10	–	60	–	3.3 V V_{DD} , Load = 25 pF

Notes

3. V_{IH} must not exceed $V_{DD} + 0.2$ V.
4. Guaranteed by characterization.

Table 6. GPIO AC Specifications

(Guaranteed by Characterization) (continued)

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID74	F _{GPIOUT1}	GPIO F _{OUT} ; 3.3 V ≤ V _{DDD} ≤ 5.5 V Fast strong mode	–	–	33	MHz	90/10%, 25 pF load, 60/40 duty cycle
SID75	F _{GPIOUT2}	GPIO F _{OUT} ; 1.71 V ≤ V _{DDD} ≤ 3.3 V Fast strong mode	–	–	16.7		90/10%, 25 pF load, 60/40 duty cycle
SID76	F _{GPIOUT3}	GPIO F _{OUT} ; 3.3 V ≤ V _{DDD} ≤ 5.5 V Slow strong mode	–	–	7		90/10%, 25 pF load, 60/40 duty cycle
SID245	F _{GPIOUT4}	GPIO F _{OUT} ; 1.71 V ≤ V _{DDD} ≤ 3.3 V Slow strong mode.	–	–	3.5		90/10%, 25 pF load, 60/40 duty cycle
SID246	F _{GPIOIN}	GPIO input operating frequency; 1.71 V ≤ V _{DDD} ≤ 5.5 V	–	–	48		90/10% V _{IO}

XRES
Table 7. XRES DC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID77	V _{IH}	Input voltage high threshold	0.7 × V _{DDD}	–	–	V	CMOS Input
SID78	V _{IL}	Input voltage low threshold	–	–	0.3 × V _{DDD}		
SID79	R _{PULLUP}	Pull-up resistor	–	60	–	kΩ	–
SID80	C _{IN}	Input capacitance	–	–	7	pF	–
SID81 ^[5]	V _{HYSXRES}	Input voltage hysteresis	–	100	–	mV	Typical hysteresis is 200 mV for V _{DD} > 4.5 V
SID82	I _{DIODE}	Current through protection diode to V _{DD} /V _{SS}	–	–	100	μA	

Table 8. XRES AC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID83 ^[5]	T _{RESETWIDTH}	Reset pulse width	1	–	–	μs	–
BID194 ^[5]	T _{RESETWAKE}	Wake-up time from reset release	–	–	2.7	ms	–

Note

5. Guaranteed by characterization.

Analog Peripherals
Table 9. Comparator DC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID84	V _{OFFSET1}	Input offset voltage, Factory trim	–	–	±10	mV	–
SID85	V _{OFFSET2}	Input offset voltage, Custom trim	–	–	±4		–
SID86	V _{HYST}	Hysteresis when enabled	–	10	35		–
SID87	V _{ICM1}	Input common mode voltage in normal mode	0	–	V _{DDD} -0.1	V	Modes 1 and 2
SID247	V _{ICM2}	Input common mode voltage in low power mode	0	–	V _{DDD}		–
SID247A	V _{ICM3}	Input common mode voltage in ultra low power mode	0	–	V _{DDD} -1.15		V _{DDD} ≥ 2.2 V at –40 °C
SID88	C _{MRR}	Common mode rejection ratio	50	–	–	dB	V _{DDD} ≥ 2.7V
SID88A	C _{MRR}	Common mode rejection ratio	42	–	–		V _{DDD} ≤ 2.7V
SID89	I _{CMP1}	Block current, normal mode	–	–	400	μA	–
SID248	I _{CMP2}	Block current, low power mode	–	–	100		–
SID259	I _{CMP3}	Block current in ultra low-power mode	–	6	28		V _{DDD} ≥ 2.2 V at –40 °C
SID90	Z _{CMP}	DC Input impedance of comparator	35	–	–	MΩ	–

Table 10. Comparator AC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID91	TRESP1	Response time, normal mode, 50 mV overdrive	–	38	110	ns	–
SID258	TRESP2	Response time, low power mode, 50 mV overdrive	–	70	200		–
SID92	TRESP3	Response time, ultra-low power mode, 200 mV overdrive	–	2.3	15	μs	V _{DDD} ≥ 2.2 V at –40 °C

CSD
Table 11. CSD and IDAC Specifications

SPEC ID#	Parameter	Description	Min	Typ	Max	Units	Details / Conditions
SYS.PER#3	VDD_RIPPLE	Max allowed ripple on power supply, DC to 10 MHz	–	–	±50	mV	$V_{DD} > 2\text{ V}$ (with ripple), 25°C T_A , Sensitivity = 0.1 pF
SYS.PER#16	VDD_RIPPLE_1.8	Max allowed ripple on power supply, DC to 10 MHz	–	–	±25	mV	$V_{DD} > 1.75\text{V}$ (with ripple), 25°C T_A , Parasitic Capacitance (C_P) < 20 pF, Sensitivity ≥ 0.4 pF
SID.CSD.BLK	ICSD	Maximum block current	–	–	4000	μA	Maximum block current for both IDACs in dynamic (switching) mode including comparators, buffer, and reference generator.
SID.CSD#15	V _{REF}	Voltage reference for CSD and Comparator	0.6	1.2	$V_{DDA} - 0.6$	V	$V_{DDA} - 0.06$ or 4.4, whichever is lower
SID.CSD#15A	VREF_EXT	External Voltage reference for CSD and Comparator	0.6		$V_{DDA} - 0.6$	V	$V_{DDA} - 0.06$ or 4.4, whichever is lower
SID.CSD#16	IDAC1IDD	IDAC1 (7-bits) block current	–	–	1750	μA	
SID.CSD#17	IDAC2IDD	IDAC2 (7-bits) block current	–	–	1750	μA	
SID308	VCSD	Voltage range of operation	1.71	–	5.5	V	1.8 V ±5% or 1.8 V to 5.5 V
SID308A	VCOMPIDAC	Voltage compliance range of IDAC	0.6	–	$V_{DDA} - 0.6$	V	$V_{DDA} - 0.06$ or 4.4, whichever is lower
SID309	IDAC1DNL	DNL	–1	–	1	LSB	
SID310	IDAC1INL	INL	–2	–	2	LSB	INL is ±5.5 LSB for $V_{DDA} < 2\text{ V}$
SID311	IDAC2DNL	DNL	–1	–	1	LSB	
SID312	IDAC2INL	INL	–2	–	2	LSB	INL is ±5.5 LSB for $V_{DDA} < 2\text{ V}$
SID313	SNR	Ratio of counts of finger to noise. Guaranteed by characterization	5	–	–	Ratio	Capacitance range of 5 to 35 pF, 0.1-pF sensitivity. All use cases. $V_{DDA} > 2\text{ V}$.
SID314	IDAC1CRT1	Output current of IDAC1 (7 bits) in low range	4.2	–	5.4	μA	LSB = 37.5-nA typ.
SID314A	IDAC1CRT2	Output current of IDAC1 (7 bits) in medium range	34	–	41	μA	LSB = 300-nA typ.
SID314B	IDAC1CRT3	Output current of IDAC1 (7 bits) in high range	275	–	330	μA	LSB = 2.4-μA typ.
SID314C	IDAC1CRT12	Output current of IDAC1 (7 bits) in low range, 2X mode	8	–	10.5	μA	LSB = 75-nA typ.
SID314D	IDAC1CRT22	Output current of IDAC1 (7 bits) in medium range, 2X mode	69	–	82	μA	LSB = 600-nA typ.
SID314E	IDAC1CRT32	Output current of IDAC1 (7 bits) in high range, 2X mode	540	–	660	μA	LSB = 4.8-μA typ.
SID315	IDAC2CRT1	Output current of IDAC2 (7 bits) in low range	4.2	–	5.4	μA	LSB = 37.5-nA typ.
SID315A	IDAC2CRT2	Output current of IDAC2 (7 bits) in medium range	34	–	41	μA	LSB = 300-nA typ.
SID315B	IDAC2CRT3	Output current of IDAC2 (7 bits) in high range	275	–	330	μA	LSB = 2.4-μA typ.
SID315C	IDAC2CRT12	Output current of IDAC2 (7 bits) in low range, 2X mode	8	–	10.5	μA	LSB = 75-nA typ.
SID315D	IDAC2CRT22	Output current of IDAC2 (7 bits) in medium range, 2X mode	69	–	82	μA	LSB = 600-nA typ.
SID315E	IDAC2CRT32	Output current of IDAC2 (7 bits) in high range, 2X mode	540	–	660	μA	LSB = 4.8-μA typ.
SID315F	IDAC3CRT13	Output current of IDAC in 8-bit mode in low range	8	–	10.5	μA	LSB = 37.5-nA typ.

Table 11. CSD and IDAC Specifications (continued)

SPEC ID#	Parameter	Description	Min	Typ	Max	Units	Details / Conditions
SID315G	IDAC3CRT23	Output current of IDAC in 8-bit mode in medium range	69	–	82	μA	LSB = 300-nA typ.
SID315H	IDAC3CRT33	Output current of IDAC in 8-bit mode in high range	540	–	660	μA	LSB = 2.4-μA typ.
SID320	IDACOFFSET	All zeroes input	–	–	1	LSB	Polarity set by Source or Sink. Offset is 2 LSBs for 37.5 nA/LSB mode
SID321	IDACGAIN	Full-scale error less offset	–	–	±10	%	
SID322	IDACMISMATCH1	Mismatch between IDAC1 and IDAC2 in Low mode	–	–	9.2	LSB	LSB = 37.5-nA typ.
SID322A	IDACMISMATCH2	Mismatch between IDAC1 and IDAC2 in Medium mode	–	–	5.6	LSB	LSB = 300-nA typ.
SID322B	IDACMISMATCH3	Mismatch between IDAC1 and IDAC2 in High mode	–	–	6.8	LSB	LSB = 2.4-μA typ.
SID323	IDACSET8	Settling time to 0.5 LSB for 8-bit IDAC	–	–	10	μs	Full-scale transition. No external load.
SID324	IDACSET7	Settling time to 0.5 LSB for 7-bit IDAC	–	–	10	μs	Full-scale transition. No external load.
SID325	CMOD	External modulator capacitor.	–	2.2	–	nF	5-V rating, X7R or NP0 cap.

Table 12. 10-bit CapSense ADC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SIDA94	A_RES	Resolution	–	–	10	bits	Auto-zeroing is required every millisecond
SIDA95	A_CHNLS_S	Number of channels - single ended	–	–	16		Defined by AMUX Bus.
SIDA97	A-MONO	Monotonicity	–	–	–	Yes	
SIDA98	A_GAINERR	Gain error	–	–	±2	%	In V_{REF} (2.4 V) mode with V_{DDA} bypass capacitance of 10 μF
SIDA99	A_OFFSET	Input offset voltage	–	–	3	mV	In V_{REF} (2.4 V) mode with V_{DDA} bypass capacitance of 10 μF
SIDA100	A_ISAR	Current consumption	–	–	0.25	mA	
SIDA101	A_VINS	Input voltage range - single ended	V_{SSA}	–	V_{DDA}	V	
SIDA103	A_INRES	Input resistance	–	2.2	–	KΩ	
SIDA104	A_INCAP	Input capacitance	–	20	–	pF	
SIDA106	A_PSR	Power supply rejection ratio	–	60	–	dB	In V_{REF} (2.4 V) mode with V_{DDA} bypass capacitance of 10 μF
SIDA107	A_TACQ	Sample acquisition time	–	1	–	μs	
SIDA108	A_CONV8	Conversion time for 8-bit resolution at conversion rate = $F_{clk}/(2^{(N+2)})$. Clock frequency = 48 MHz.	–	–	21.3	μs	Does not include acquisition time. Equivalent to 44.8 ksp/s including acquisition time.
SIDA108A	A_CONV10	Conversion time for 10-bit resolution at conversion rate = $F_{clk}/(2^{(N+2)})$. Clock frequency = 48 MHz.	–	–	85.3	μs	Does not include acquisition time. Equivalent to 11.6 ksp/s including acquisition time.

Table 12. 10-bit CapSense ADC Specifications (continued)

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SIDA109	A_SND	Signal-to-noise and Distortion ratio (SINAD)	–	61	–	dB	With 10-Hz input sine wave, external 2.4-V reference, V _{REF} (2.4 V) mode
SIDA110	A_BW	Input bandwidth without aliasing	–	–	22.4	kHz	8-bit resolution
SIDA111	A_INL	Integral Non Linearity. 1 ksps	–	–	2	LSB	V _{REF} = 2.4 V or greater
SIDA112	A_DNL	Differential Non Linearity. 1 ksps	–	–	1	LSB	

Digital Peripherals

Timer Counter Pulse-Width Modulator (TCPWM)

Table 13. TCPWM Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID.TCPWM.1	ITCPWM1	Block current consumption at 3 MHz	–	–	45	μA	All modes (TCPWM)
SID.TCPWM.2	ITCPWM2	Block current consumption at 12 MHz	–	–	155		All modes (TCPWM)
SID.TCPWM.2A	ITCPWM3	Block current consumption at 48 MHz	–	–	650		All modes (TCPWM)
SID.TCPWM.3	TCPWM _{FREQ}	Operating frequency	–	–	F _c	MHz	F _c max = CLK_SYS Maximum = 48 MHz
SID.TCPWM.4	TPWM _{ENEXT}	Input trigger pulse width	2/F _c	–	–	ns	For all trigger events ^[6]
SID.TCPWM.5	TPWM _{EXT}	Output trigger pulse widths	2/F _c	–	–		Minimum possible width of Overflow, Underflow, and CC (Counter equals Compare value) outputs
SID.TCPWM.5A	TC _{RES}	Resolution of counter	1/F _c	–	–		Minimum time between successive counts
SID.TCPWM.5B	PWM _{RES}	PWM resolution	1/F _c	–	–		Minimum pulse width of PWM Output
SID.TCPWM.5C	Q _{RES}	Quadrature inputs resolution	1/F _c	–	–		Minimum pulse width between Quadrature phase inputs

Note

6. Trigger events can be Stop, Start, Reload, Count, Capture, or Kill depending on which mode of operation is selected.

I^2C
Table 14. Fixed I^2C DC Specifications^[7]

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID149	I_{I2C1}	Block current consumption at 100 kHz	–	–	50	μA	–
SID150	I_{I2C2}	Block current consumption at 400 kHz	–	–	135		–
SID151	I_{I2C3}	Block current consumption at 1 Mbps	–	–	310		–
SID152	I_{I2C4}	I^2C enabled in Deep Sleep mode	–	–	1.4		

Table 15. Fixed I^2C AC Specifications^[7]

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID153	F_{I2C1}	Bit rate	–	–	1	Msps	–

Table 16. SPI DC Specifications^[7]

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID163	ISPI1	Block current consumption at 1 Mbps	–	–	360	μA	–
SID164	ISPI2	Block current consumption at 4 Mbps	–	–	560		–
SID165	ISPI3	Block current consumption at 8 Mbps	–	–	600		–

Table 17. SPI AC Specifications^[7]

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID166	FSPI	SPI operating frequency (Master; 6X Oversampling)	–	–	8	MHz	
Fixed SPI Master Mode AC Specifications							
SID167	TDMO	MOSI Valid after SClock driving edge	–	–	15	ns	–
SID168	TDSI	MISO Valid before SClock capturing edge	20	–	–		Full clock, late MISO sampling
SID169	THMO	Previous MOSI data hold time	0	–	–		Referred to Slave capturing edge
Fixed SPI Slave Mode AC Specifications							
SID170	TDMI	MOSI Valid before Scklock Capturing edge	40	–	–	ns	–
SID171	TDSO	MISO Valid after Scklock driving edge	–	–	42 + 3*Tcpu		T _{CPU} = 1/F _{CPU}
SID171A	TDSO_EXT	MISO Valid after Scklock driving edge in Ext. Clk mode	–	–	48		–
SID172	THSO	Previous MISO data hold time	0	–	–		–
SID172A	TSSELSSCK	SSEL Valid to first SCK Valid edge	–	–	100	ns	–

Note

7. Guaranteed by characterization.

Memory

Table 22. Flash DC Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID173	V _{PE}	Erase and program voltage	1.71	–	5.5	V	–

Table 23. Flash AC Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID174	T _{ROWWRITE} ^[9]	Row (block) write time (erase and program)	–	–	20	ms	Row (block) = 128 bytes
SID175	T _{ROWERASE} ^[9]	Row erase time	–	–	16		–
SID176	T _{ROWPROGRAM} ^[9]	Row program time after erase	–	–	4		–
SID178	T _{BULKERASE} ^[9]	Bulk erase time (32 KB)	–	–	35		–
SID180 ^[10]	T _{DEVPROG} ^[9]	Total device program time	–	–	7	Seconds	–
SID181 ^[10]	F _{END}	Flash endurance	100 K	–	–	Cycles	–
SID182 ^[10]	F _{RET}	Flash retention. T _A ≤ 55 °C, 100 K P/E cycles	20	–	–	Years	–
SID182A ^[10]	–	Flash retention. T _A ≤ 85 °C, 10 K P/E cycles	10	–	–		–
SID256	TWS48	Number of Wait states at 48 MHz	2	–	–		CPU execution from Flash
SID257	TWS24	Number of Wait states at 24 MHz	1	–	–		CPU execution from Flash

System Resources

Power-on Reset (POR)

Table 24. Power On Reset (PRES)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID.CLK#6	SR_POWER_UP	Power supply slew rate	1	–	67	V/ms	At power-up
SID185 ^[10]	V _{RISEIPOR}	Rising trip voltage	0.80	–	1.5	V	–
SID186 ^[10]	V _{FALLIPOR}	Falling trip voltage	0.70	–	1.4		–

Table 25. Brown-out Detect (BOD) for V_{CCD}

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID190 ^[10]	V _{FALLPPOR}	BOD trip voltage in active and sleep modes	1.48	–	1.62	V	–
SID192 ^[10]	V _{FALLDPSLP}	BOD trip voltage in Deep Sleep	1.11	–	1.5		–

Notes

9. It can take as much as 20 milliseconds to write to Flash. During this time the device should not be Reset, or Flash operations will be interrupted and cannot be relied on to have completed. Reset sources include the XRES pin, software resets, CPU lockup states and privilege violations, improper power supply levels, and watchdogs. Make certain that these are not inadvertently activated.

10. Guaranteed by characterization.

SWD Interface

Table 26. SWD Interface Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID213	F_SWDCCLK1	$3.3\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	–	–	14	MHz	SWDCCLK $\leq$ 1/3 CPU clock frequency
SID214	F_SWDCCLK2	$1.71\text{ V} \leq V_{DD} \leq 3.3\text{ V}$	–	–	7		SWDCCLK $\leq$ 1/3 CPU clock frequency
SID215 ^[11]	T_SWDI_SETUP	$T = 1/f_{\text{SWDCCLK}}$	$0.25 \cdot T$	–	–	ns	–
SID216 ^[11]	T_SWDI_HOLD	$T = 1/f_{\text{SWDCCLK}}$	$0.25 \cdot T$	–	–		–
SID217 ^[11]	T_SWDO_VALID	$T = 1/f_{\text{SWDCCLK}}$	–	–	$0.5 \cdot T$		–
SID217A ^[11]	T_SWDO_HOLD	$T = 1/f_{\text{SWDCCLK}}$	1	–	–		–

Internal Main Oscillator

Table 27. IMO DC Specifications

(Guaranteed by Design)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID218	I_IMO1	IMO operating current at 48 MHz	–	–	250	μA	–
SID219	I_IMO2	IMO operating current at 24 MHz	–	–	180	μA	–

Table 28. IMO AC Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID223	F_IMOTOL1	Frequency variation at 24, 32, and 48 MHz (trimmed)	–	–	± 2	%	
SID226	T_STARTIMO	IMO startup time	–	–	7	μs	–
SID228	T_JITRMSIMO2	RMS jitter at 24 MHz	–	145	–	ps	–

Internal Low-Speed Oscillator

Table 29. ILO DC Specifications

(Guaranteed by Design)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID231 ^[11]	I_ILO1	ILO operating current	–	0.3	1.05	μA	–

Table 30. ILO AC Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID234 ^[11]	T_STARTILO1	ILO startup time	–	–	2	ms	–
SID236 ^[11]	T_ILODUTY	ILO duty cycle	40	50	60	%	–
SID237	F_ILOTRIM1	ILO frequency range	20	40	80	kHz	–

Note

11. Guaranteed by characterization.

Ordering Information

The PSoC 4000S part numbers and features are listed in the following table.

Table 35. PSoC 4000S Ordering Information

Category	MPN	Features												Package				
		Max CPU Speed (MHz)	Flash (KB)	SRAM (KB)	Opamp (CTBm)	CapSense	10-bit CSD ADC	12-bit SAR ADC	LP Comparators	TCPWM Blocks	SCB Blocks	Smart I/Os	GPIO	WLCSP (0.35-mm pitch)	24-Pin QFN	32-Pin QFN	40-Pin QFN	48-Pin TQFP
4024	CY8C4024FNI-S402	24	16	2	0	0	1	0	2	5	2	8	21	✓				
	CY8C4024LQI-S401	24	16	2	0	0	1	0	2	5	2	8	19		✓			
	CY8C4024LQI-S402	24	16	2	0	0	1	0	2	5	2	16	27			✓		
	CY8C4024LQI-S403	24	16	2	0	0	1	0	2	5	2	16	34				✓	
	CY8C4024AZI-S403	24	16	2	0	0	1	0	2	5	2	16	36					✓
	CY8C4024FNI-S412	24	16	2	0	1	1	0	2	5	2	8	21	✓				
	CY8C4024LQI-S411	24	16	2	0	1	1	0	2	5	2	8	19		✓			
	CY8C4024LQI-S412	24	16	2	0	1	1	0	2	5	2	16	27			✓		
	CY8C4024LQI-S413	24	16	2	0	1	1	0	2	5	2	16	34				✓	
	CY8C4024AZI-S413	24	16	2	0	1	1	0	2	5	2	16	36					✓
4025	CY8C4025FNI-S402	24	32	4	0	0	1	0	2	5	2	8	21	✓				
	CY8C4025LQI-S401	24	32	4	0	0	1	0	2	5	2	8	19		✓			
	CY8C4025LQI-S402	24	32	4	0	0	1	0	2	5	2	16	27			✓		
	CY8C4025AZI-S403	24	32	4	0	0	1	0	2	5	2	16	36					✓
	CY8C4025FNI-S412	24	32	4	0	1	1	0	2	5	2	8	21	✓				
	CY8C4025LQI-S411	24	32	4	0	1	1	0	2	5	2	8	19		✓			
	CY8C4025LQI-S412	24	32	4	0	1	1	0	2	5	2	16	27			✓		
	CY8C4025AZI-S413	24	32	4	0	1	1	0	2	5	2	16	36					✓
4045	CY8C4045FNI-S412	48	32	4	0	1	1	0	2	5	2	8	21	✓				
	CY8C4045LQI-S411	48	32	4	0	1	1	0	2	5	2	8	19		✓			
	CY8C4045LQI-S412	48	32	4	0	1	1	0	2	5	2	16	27			✓		
	CY8C4045AZI-S413	48	32	4	0	1	1	0	2	5	2	16	36					✓

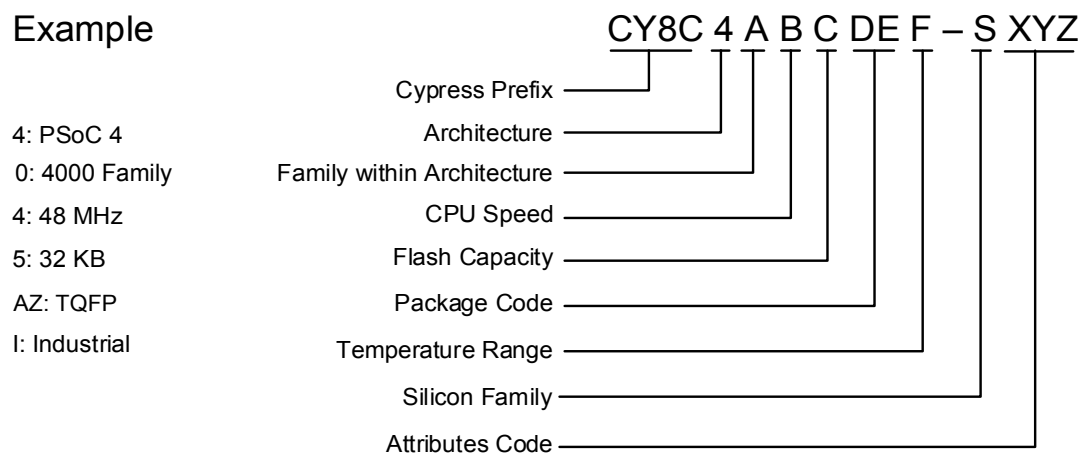
The nomenclature used in the preceding table is based on the following part numbering convention:

Field	Description	Values	Meaning
CY8C	Cypress Prefix		
4	Architecture	4	PSoC 4
A	Family	0	4000 Family
B	CPU Speed	2	24 MHz
		4	48 MHz

Field	Description	Values	Meaning
C	Flash Capacity	4	16 KB
		5	32 KB
		6	64 KB
		7	128 KB
DE	Package Code	AX	TQFP (0.8-mm pitch)
		AZ	TQFP (0.5-mm pitch)
		LQ	QFN
		PV	SSOP
		FN	CSP
F	Temperature Range	I	Industrial
S	Silicon Family	S	PSoC 4A-S1, PSoC 4A-S2
		M	PSoC 4A-M
		L	PSoC 4A-L
		BL	PSoC 4A-BLE
XYZ	Attributes Code	000-999	Code of feature set in the specific family

The following is an example of a part number:

Example



Packaging

The PSoC 4000S will be offered in 48-pin TQFP, 40-pin QFN, 32-pin QFN, 24-pin QFN, and 25-ball WLCSP packages.

Package dimensions and Cypress drawing numbers are in the following table.

Table 36. Package List

Spec ID#	Package	Description	Package Dwg
BID20	48-pin TQFP	7 × 7 × 1.4 mm height with 0.5-mm pitch	51-85135
BID27	40-pin QFN	6 × 6 × 0.6 mm height with 0.5-mm pitch	001-80659
BID34A	32-pin QFN	5 × 5 × 0.6 mm height with 0.5-mm pitch	001-42168
BID34	24-pin QFN	4 × 4 × 0.6 mm height with 0.5-mm pitch	001-13937
BID34F	25-ball WLCSP	2.02 × 1.93 × 0.48 mm height with 0.35-mm pitch	002-09957

Table 37. Package Thermal Characteristics

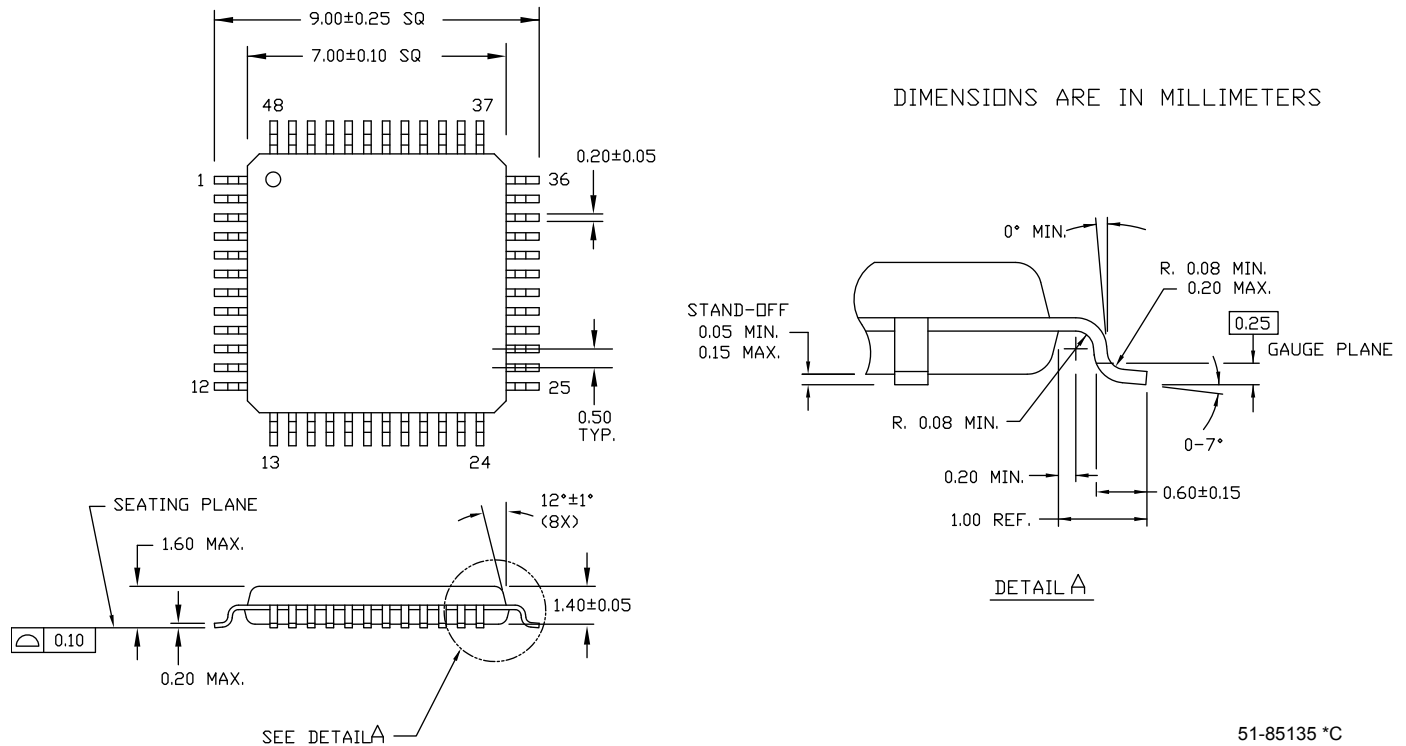
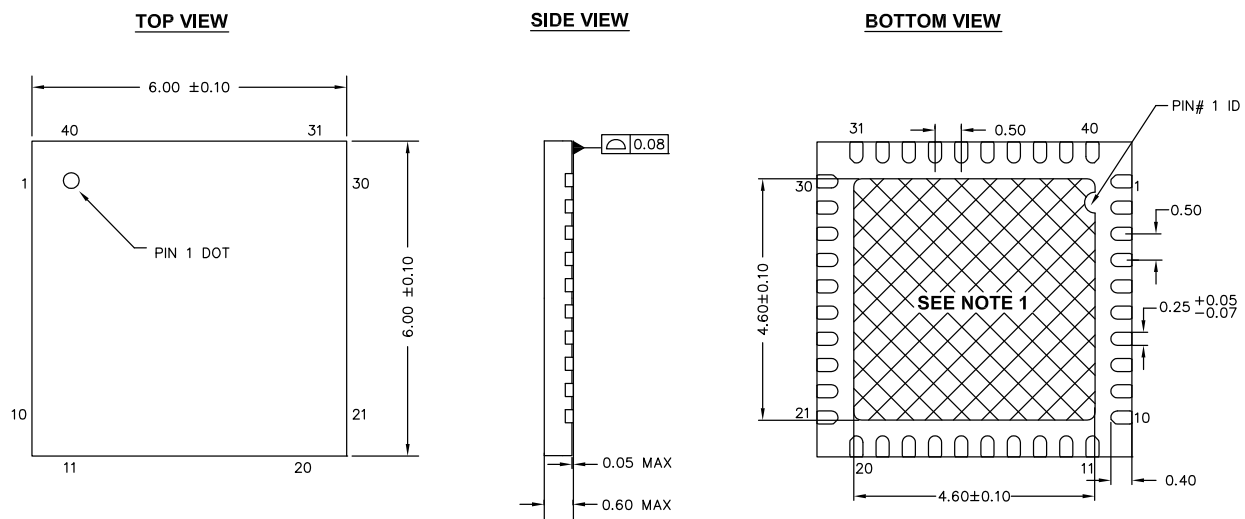
Parameter	Description	Package	Min	Typ	Max	Units
T _A	Operating ambient temperature		−40	25	85	°C
T _J	Operating junction temperature		−40	—	100	°C
T _{JA}	Package θ _{JA}	48-pin TQFP	—	73.5	—	°C/Watt
T _{JC}	Package θ _{JC}	48-pin TQFP	—	33.5	—	°C/Watt
T _{JA}	Package θ _{JA}	40-pin QFN	—	17.8	—	°C/Watt
T _{JC}	Package θ _{JC}	40-pin QFN	—	2.8	—	°C/Watt
T _{JA}	Package θ _{JA}	32-pin QFN	—	20.8	—	°C/Watt
T _{JC}	Package θ _{JC}	32-pin QFN	—	5.9	—	°C/Watt
T _{JA}	Package θ _{JA}	24-pin QFN	—	21.7	—	°C/Watt
T _{JC}	Package θ _{JC}	24-pin QFN	—	5.6	—	°C/Watt
T _{JA}	Package θ _{JA}	25-ball WLCSP	—	54.6	—	°C/Watt
T _{JC}	Package θ _{JC}	25-ball WLCSP	—	0.5	—	°C/Watt

Table 38. Solder Reflow Peak Temperature

Package	Maximum Peak Temperature	Maximum Time at Peak Temperature
All	260 °C	30 seconds

Table 39. Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-020

Package	MSL
All except WLCSP	MSL 3
25-ball WLCSP	MSL 1

Package Diagrams
Figure 5. 48-pin TQFP Package Outline

Figure 6. 40-pin QFN Package Outline

NOTES:

1.  HATCH AREA IS SOLDERABLE EXPOSED PAD
2. REFERENCE JEDEC # MO-248
3. PACKAGE WEIGHT: 68 ±2 mg
4. ALL DIMENSIONS ARE IN MILLIMETERS

001-80659 *A

Acronyms

Table 40. Acronyms Used in this Document

Acronym	Description
abus	analog local bus
ADC	analog-to-digital converter
AG	analog global
AHB	AMBA (advanced microcontroller bus architecture) high-performance bus, an ARM data transfer bus
ALU	arithmetic logic unit
AMUXBUS	analog multiplexer bus
API	application programming interface
APSR	application program status register
ARM®	advanced RISC machine, a CPU architecture
ATM	automatic thump mode
BW	bandwidth
CAN	Controller Area Network, a communications protocol
CMRR	common-mode rejection ratio
CPU	central processing unit
CRC	cyclic redundancy check, an error-checking protocol
DAC	digital-to-analog converter, see also IDAC, VDAC
DFB	digital filter block
DIO	digital input/output, GPIO with only digital capabilities, no analog. See GPIO.
DMIPS	Dhrystone million instructions per second
DMA	direct memory access, see also TD
DNL	differential nonlinearity, see also INL
DNU	do not use
DR	port write data registers
DSI	digital system interconnect
DWT	data watchpoint and trace
ECC	error correcting code
ECO	external crystal oscillator
EEPROM	electrically erasable programmable read-only memory
EMI	electromagnetic interference
EMIF	external memory interface
EOC	end of conversion
EOF	end of frame
EPSR	execution program status register
ESD	electrostatic discharge

Table 40. Acronyms Used in this Document *(continued)*

Acronym	Description
ETM	embedded trace macrocell
FIR	finite impulse response, see also IIR
FPB	flash patch and breakpoint
FS	full-speed
GPIO	general-purpose input/output, applies to a PSoC pin
HVI	high-voltage interrupt, see also LVI, LVD
IC	integrated circuit
IDAC	current DAC, see also DAC, VDAC
IDE	integrated development environment
I ² C, or IIC	Inter-Integrated Circuit, a communications protocol
IIR	infinite impulse response, see also FIR
ILO	internal low-speed oscillator, see also IMO
IMO	internal main oscillator, see also ILO
INL	integral nonlinearity, see also DNL
I/O	input/output, see also GPIO, DIO, SIO, USBIO
IPOR	initial power-on reset
IPSR	interrupt program status register
IRQ	interrupt request
ITM	instrumentation trace macrocell
LCD	liquid crystal display
LIN	Local Interconnect Network, a communications protocol.
LR	link register
LUT	lookup table
LVD	low-voltage detect, see also LVI
LVI	low-voltage interrupt, see also HVI
LVTTTL	low-voltage transistor-transistor logic
MAC	multiply-accumulate
MCU	microcontroller unit
MISO	master-in slave-out
NC	no connect
NMI	nonmaskable interrupt
NRZ	non-return-to-zero
NVIC	nested vectored interrupt controller
NVL	nonvolatile latch, see also WOL
opamp	operational amplifier
PAL	programmable array logic, see also PLD

Table 40. Acronyms Used in this Document *(continued)*

Acronym	Description
PC	program counter
PCB	printed circuit board
PGA	programmable gain amplifier
PHUB	peripheral hub
PHY	physical layer
PICU	port interrupt control unit
PLA	programmable logic array
PLD	programmable logic device, see also PAL
PLL	phase-locked loop
PMDD	package material declaration data sheet
POR	power-on reset
PRES	precise power-on reset
PRS	pseudo random sequence
PS	port read data register
PSoC [®]	Programmable System-on-Chip [™]
PSRR	power supply rejection ratio
PWM	pulse-width modulator
RAM	random-access memory
RISC	reduced-instruction-set computing
RMS	root-mean-square
RTC	real-time clock
RTL	register transfer language
RTR	remote transmission request
RX	receive
SAR	successive approximation register
SC/CT	switched capacitor/continuous time
SCL	I ² C serial clock
SDA	I ² C serial data
S/H	sample and hold
SINAD	signal to noise and distortion ratio
SIO	special input/output, GPIO with advanced features. See GPIO.
SOC	start of conversion
SOF	start of frame
SPI	Serial Peripheral Interface, a communications protocol
SR	slew rate
SRAM	static random access memory
SRES	software reset
SWD	serial wire debug, a test protocol

Table 40. Acronyms Used in this Document *(continued)*

Acronym	Description
SWV	single-wire viewer
TD	transaction descriptor, see also DMA
THD	total harmonic distortion
TIA	transimpedance amplifier
TRM	technical reference manual
TTL	transistor-transistor logic
TX	transmit
UART	Universal Asynchronous Transmitter Receiver, a communications protocol
UDB	universal digital block
USB	Universal Serial Bus
USBIO	USB input/output, PSoC pins used to connect to a USB port
VDAC	voltage DAC, see also DAC, IDAC
WDT	watchdog timer
WOL	write once latch, see also NVL
WRES	watchdog timer reset
XRES	external reset I/O pin
XTAL	crystal

Revision History

Description Title: PSoC [®] 4: PSoC 4000S Family Datasheet Programmable System-on-Chip (PSoC) Document Number: 002-00123				
Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	4883809	WKA	08/28/2015	New datasheet
*A	4992376	WKA	10/30/2015	Updated Pinouts . Added $V_{DD} \geq 2.2V$ at $-40^{\circ}C$ under Conditions for specs SID247A, SID90, SID92. Updated Table 12 . Updated Ordering Information .
*B	5037826	SLAN	12/08/2015	Changed datasheet status to Preliminary
*C	5104369	WKA	01/27/2016	Added Errata. Added 25 WLCSP package details. Updated theta J_A and J_C values for all packages.
*D	5139206	WKA	02/16/2016	Updated copyright information at the end of the document.
*E	5173961	WKA	03/15/2016	Updated Pinouts . Updated values for SID79, BID194, SID175, and SID176. Updated CSD and IDAC Specifications . Updated 10-bit CapSense ADC Specifications .
*F	5268662	WKA	05/12/2016	Updated Alternate Pin Functions . Updated the following specs: SID310, SID312, SID313, SID314, SID314C, SID314D, SID314E, SID315, SID315C, SID315D, SID315E, SID322A, SID322B, SIDA109. Removed Errata section. Updated the Cypress logo and copyright information based on the template.
*G	5330930	WKA	07/27/2016	Updated LCD Segment Drive . Updated SID60 conditions. Updated IDD specs. Corrected package dimensions for WLCSP package and added WLCSP MSL condition. Moved datasheet status to Final.
*H	5415365	WKA	09/14/2016	Added 40-pin QFN pin and package details. Updated IDD spec values in DC Specifications .
*I	5561833	WKA	01/09/2017	Changed PRGIO references to Smart I/O.
*J	5704046	GNKK	04/26/2017	Updated the Cypress logo and copyright information.